



Transformer design consideration for Full Bridge Phase Shift

José M. Molina

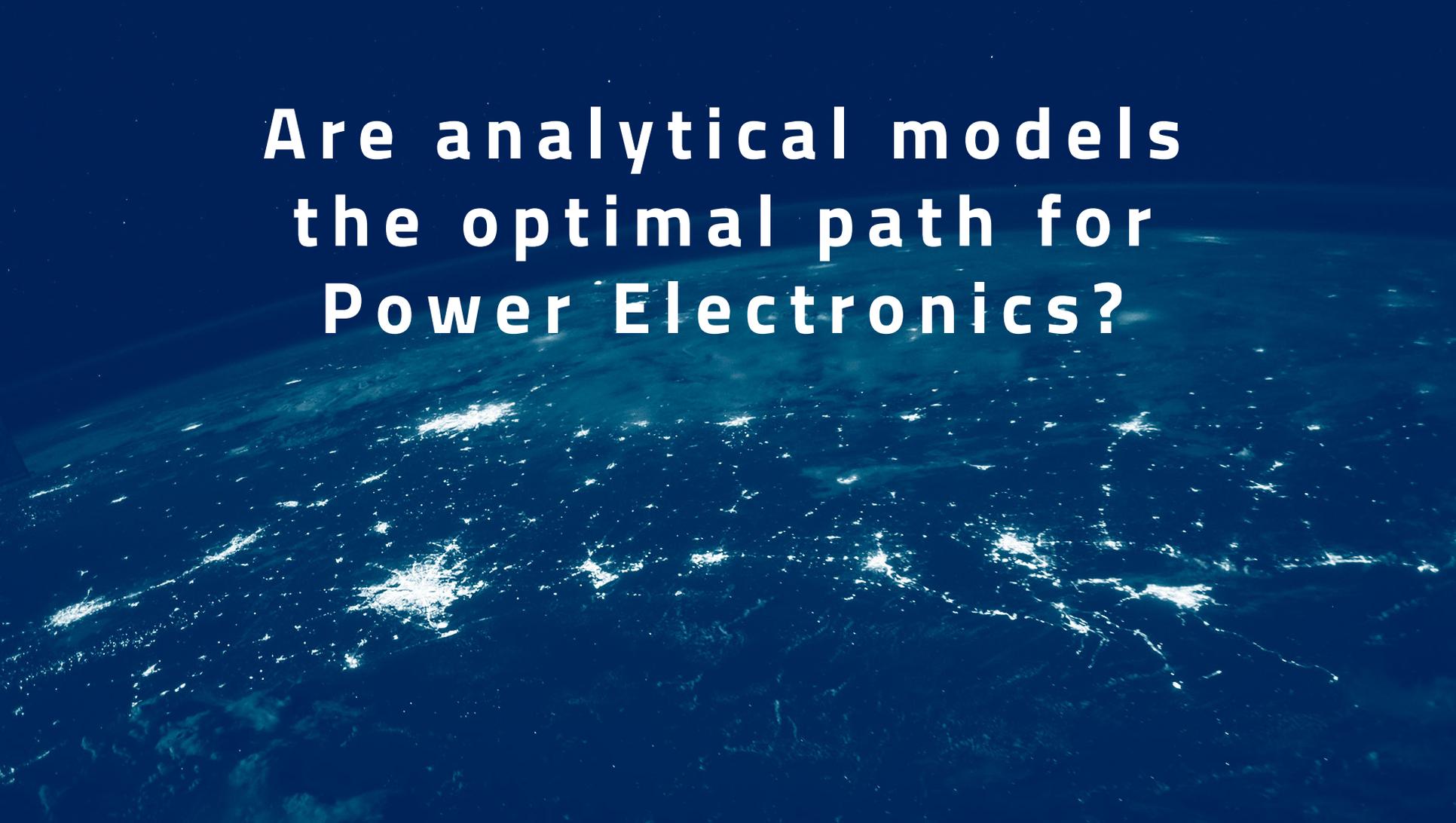
IEEE APEC 2020: PSMA Industry Session

Design of Magnetics for Different Circuit Topologies

17 March 2020, New Orleans, USA



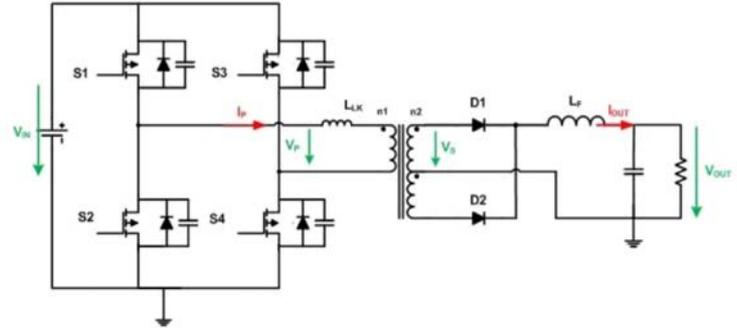
**Are analytical models
the optimal path for
Power Electronics?**

An aerial photograph of the Earth's ocean surface, showing a vast expanse of dark blue water with numerous whitecaps and small waves. The perspective is from a high altitude, looking down at the curvature of the planet. The lighting is bright, creating a shimmering effect on the water's surface.

Full-Bridge Phase Shift (FBPS)

The main features of the FBPS power converter are:

- 4 switches + (2 or 4) diodes
- Galvanic Isolation
- Typical topology for power levels $>300W$
- High efficiency
- Suitable as a Voltage or current source



FBPS relevant publications

Some of the relevant publications in the literature related with this converter before becoming an industry standard

Sabate '90

- ZVS conditions
- Effective duty cycle

DESIGN CONSIDERATIONS FOR HIGH-VOLTAGE HIGH-POWER FULL-BRIDGE ZERO-VOLTAGE-SWITCHED PWM CONVERTER

J. A. Sabate, V. Vlatkovic, R. B. Ridley, F. C. Lee and B. H. Lee

Virginia Power Electronics Center,
The Faculty Department of Electrical Engineering,
Virginia Polytechnic Institute,
Blacksburg, Virginia 24061

ABSTRACT

The paper presents a novel zero-voltage-switching (ZVS) converter topology for high-voltage, high-power applications. The design parameters based on the analysis are presented and the results from the most advanced circuit design considerations for a high-power, high-voltage application are analyzed. The results of the analysis are verified using a high-voltage, high-power

1. INTRODUCTION

The achievement of efficient high-frequency power conversion requires reduction of switching losses. Conventional resonant converters can provide zero-voltage switching (ZVS) or zero-voltage switching (ZVS). They provide a wide range of design control from reducing the commutation of the filter capacitor inductance to soft-switching of the power transistors and diodes. However, the high-frequency resonant converter does not have the high-power and high-voltage capabilities. The resonant converter cannot handle resonant frequencies (10-15) MHz, and active ZVS is not possible. Hence, it is in the region of resonant converter design.

When conventional PWM converters are operated at higher frequencies, the stored energy in the parasitic inductances of the converter produces an especially pronounced effect in high-power, high-voltage applications. Such an effect is the voltage overshoot across the power transistors and diodes.

A recently proposed zero-voltage-switching (ZVS) full-bridge PWM converter provides a wide range of design control from reducing the commutation of the filter capacitor inductance to soft-switching of the power transistors and diodes. The design parameters based on the analysis are presented and the results from the most advanced circuit design considerations for a high-power, high-voltage application are analyzed. The results of the analysis are verified using a high-voltage, high-power

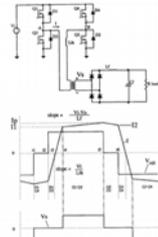


Fig. 1. 18-kV PWM converter and primary and secondary waveforms.

A NOVEL SOFT-SWITCHING FULL-BRIDGE DC/DC CONVERTER: ANALYSIS, DESIGN CONSIDERATIONS, AND EXPERIMENTAL RESULTS AT 1.5 kW, 100 kHz

Richard Redl*

Nathan O. Sokal**

Leslie Balogh**

*GE S.A.,
Energy Solutions,
1700 Channahon
Bldg. 2000
Channahon, IL 61610-2000

**Texas Instruments, Inc.,
800 Westchase Avenue,
League City, TX 77502-0002,
U.S.A.,
817.282.8000

ABSTRACT

The addition of an external commutating inductor and two diodes to the phase-shifted PWM full-bridge converter substantially reduces the switching losses of the converter and the snubber losses under all loading conditions. We give analysis, practical design considerations, and experimental results for a 1.5-kW converter with 100-kHz switching, operating at 100-kHz switching frequency and 90% efficiency.

1. INTRODUCTION

The switching losses in DC/DC converters can be reduced by using soft-switching or quasi-resonant or fully resonant converters or soft-switching techniques. Soft-switching is preferred because of these advantages:

- simpler control circuits
- simpler control
- better exploitation of the power transistors and rectifier diodes
- high efficiency
- low EMI

All power levels high enough to justify the use of four conventional transistors, probably the low-current active soft-switching forward converter (1-2, 3B, 10). This converter is controlled by phase-shifted full-bridge PWM, as compared to the parallel-resonant, the full-bridge forward converter with inductor, or other converter.

The resonant inductor of the controlled switches in the full-bridge soft-switching converter can be made smaller than in the parallel-resonant converter. However, the switching losses of the converter diodes are not eliminated appreciably. The introduction of the resonant inductor of the transformer causes voltage overshoot and ringing. This can lead to excessive transient losses, EMI, and failure of the converter. The severity of the problem increases with increasing switching frequency. Hence, the diode reverse recovery time increases with increasing voltage rating.

Redl '90

- Clamping Diode
- Lext

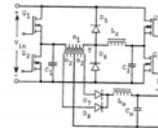


Fig. 1. Full-bridge soft-switching DC/DC converter with clamping diode and external inductor.



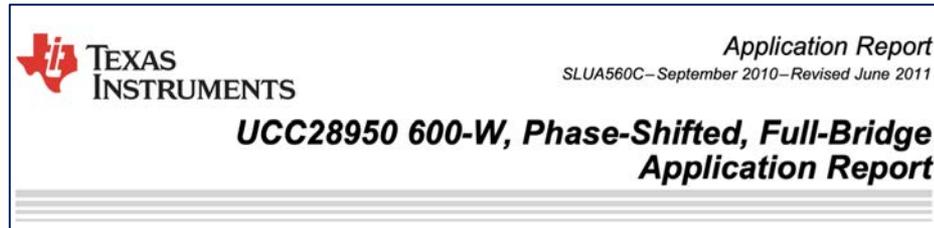
J. A. Sabate, V. Vlatkovic, R. B. Ridley and F. C. Lee, "High-voltage, high-power, ZVS, full-bridge PWM converter employing an active snubber," [Proceedings] APEC '91: Sixth Annual Applied Power Electronics Conference and Exhibition, Dallas, TX, USA, 1991, pp. 158-163

R. Redl, N. O. Sokal and L. Balogh, "A novel soft-switching full-bridge DC/DC converter: Analysis, design considerations, and experimental results at 1.5 kW, 100 kHz," 21st Annual IEEE Conference on Power Electronics Specialists, San Antonio, TX, USA, 1990, pp. 162-172.

FBPS relevant publications

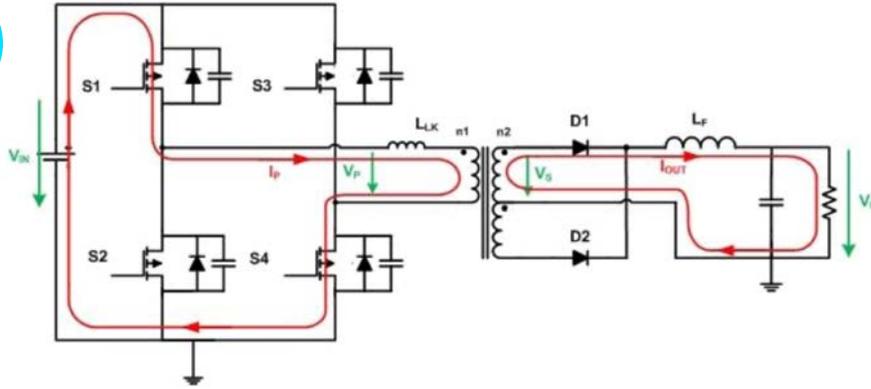
After the researchers have make their publications, industry started to create design guidelines.

Semiconductor industry has leathered the publication of app notes for Phase Shift Full Bridge converter using their chips.

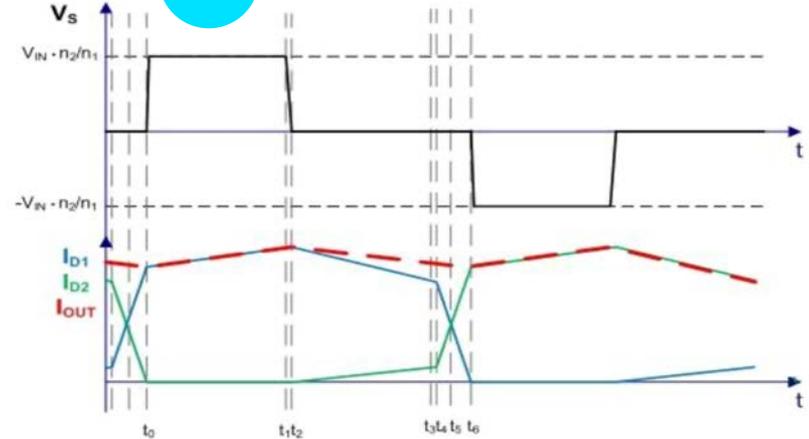


FBPS intervals

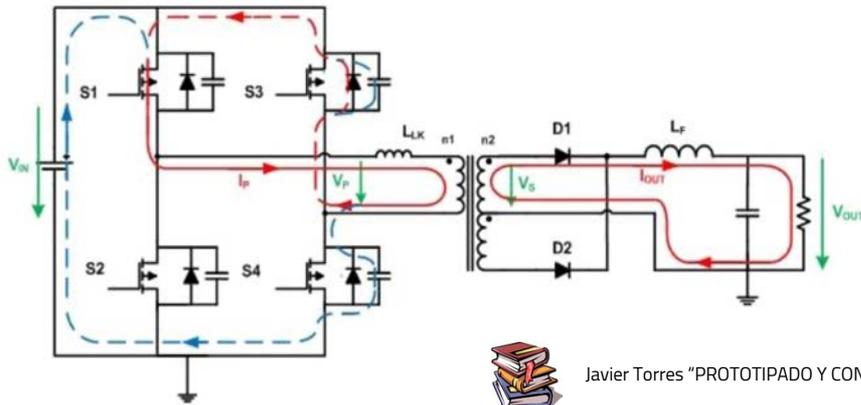
1



1



2

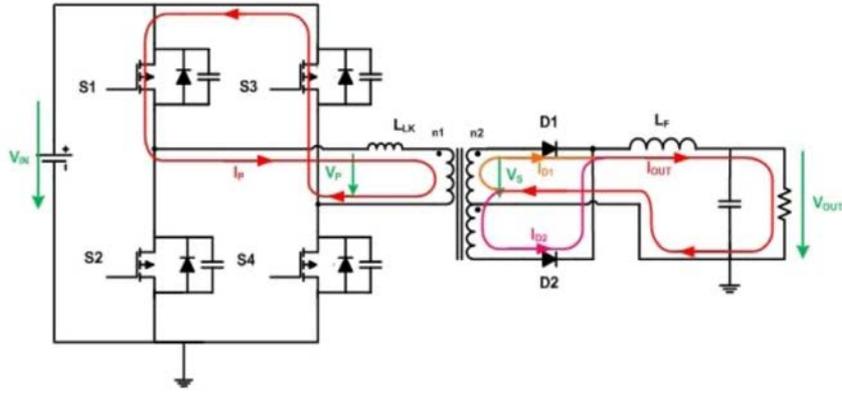


2

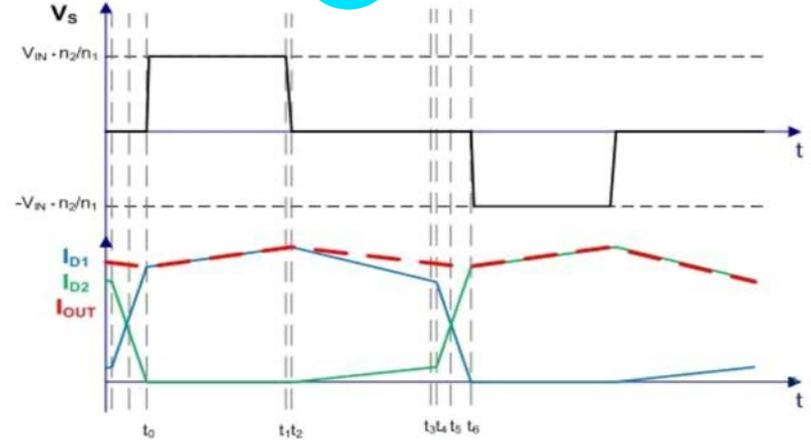


FBPS intervals

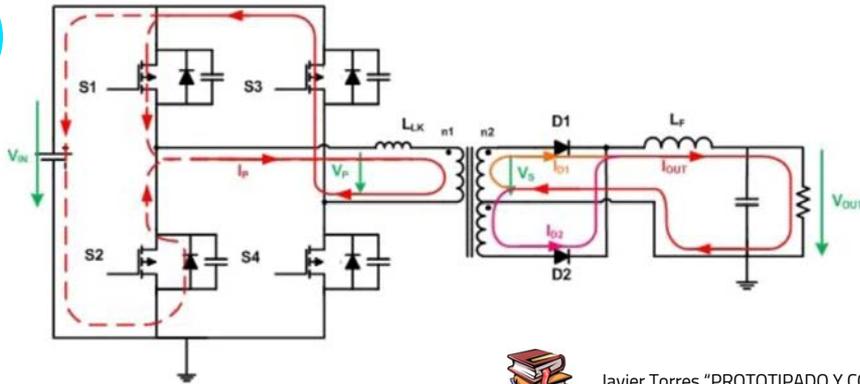
3



3



4

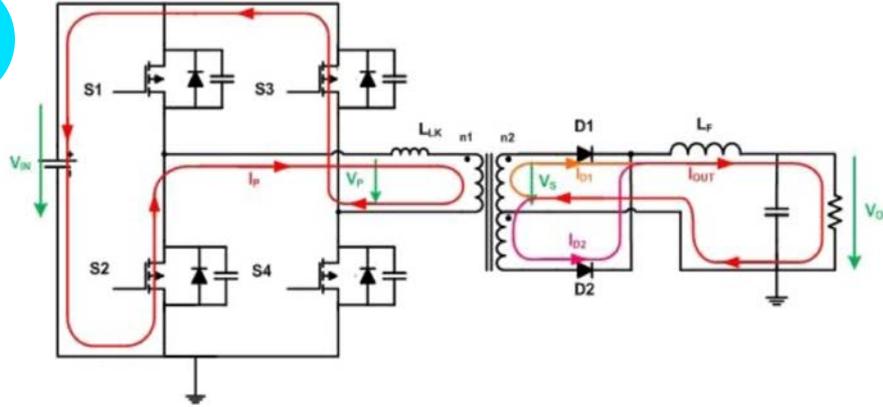


4

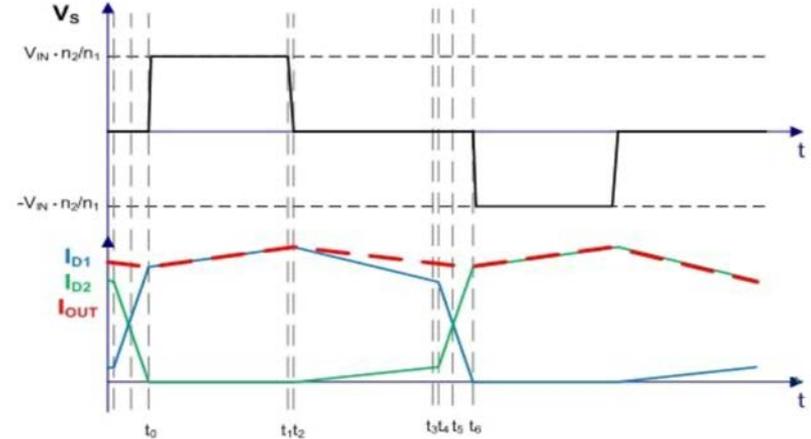


FBPS intervals

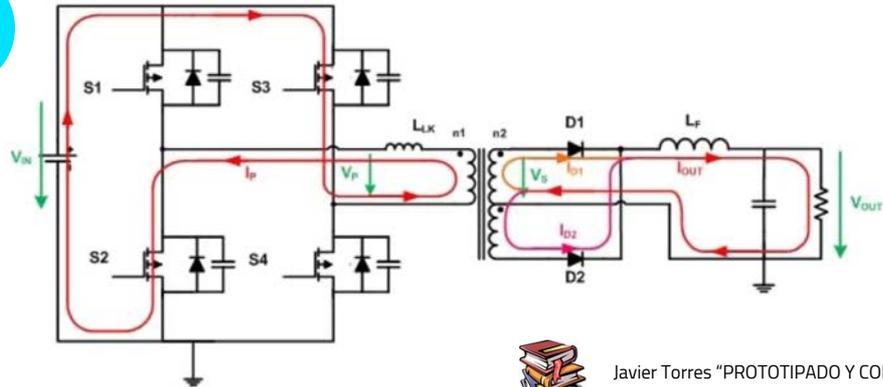
5



5



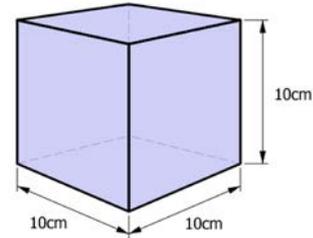
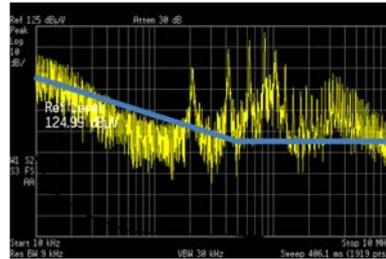
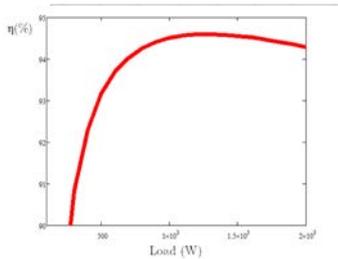
6



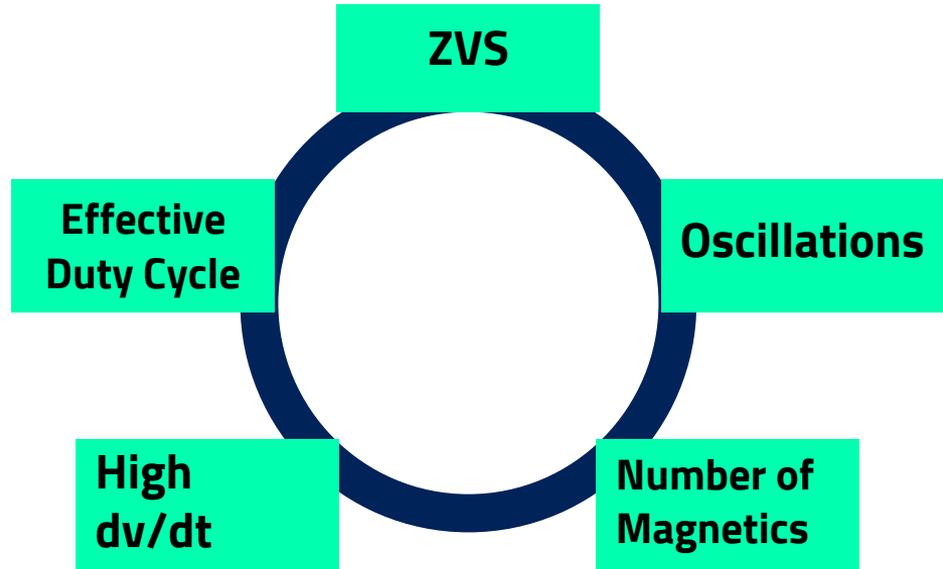
6



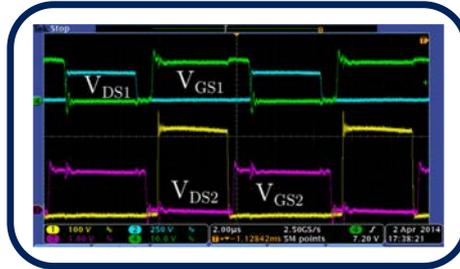
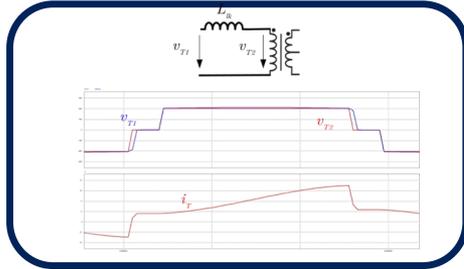
Design goals



Key parameters of the design



Key parameters of the design



ZVS

Effective Duty Cycle

Oscillations



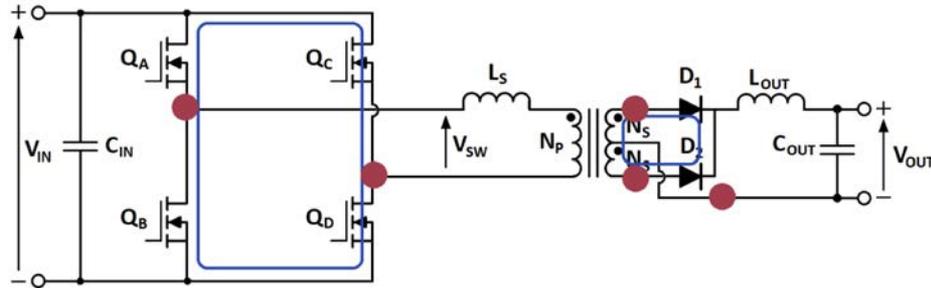
High dv/dt

Number of Magnetics



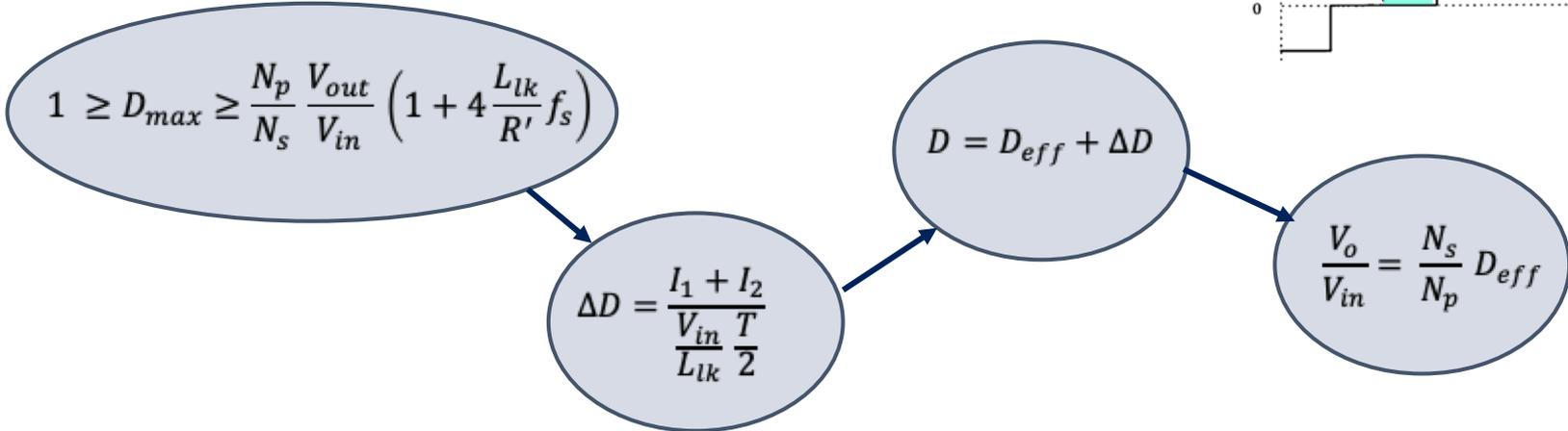
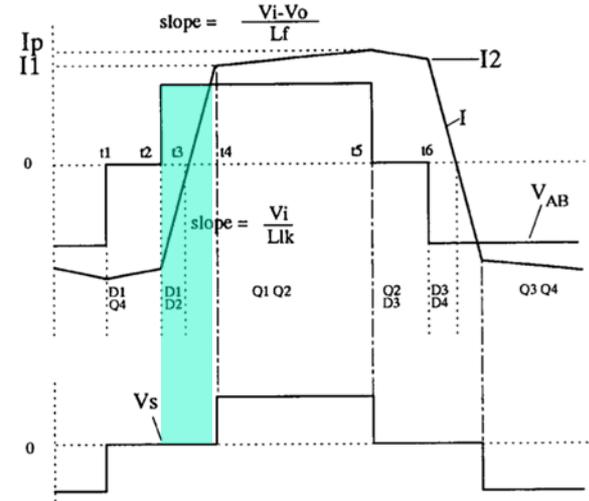
High dV/dT

- Due to the High dv/dt in the nodes A and B, the layout connections should be designed to minimize the distances as much as possible.
- Additionally, the high di/dt during the transients affects the losses in the magnetics.
- Classical steinmetz equations are not suitable and the modified steimetz or other models could be used.



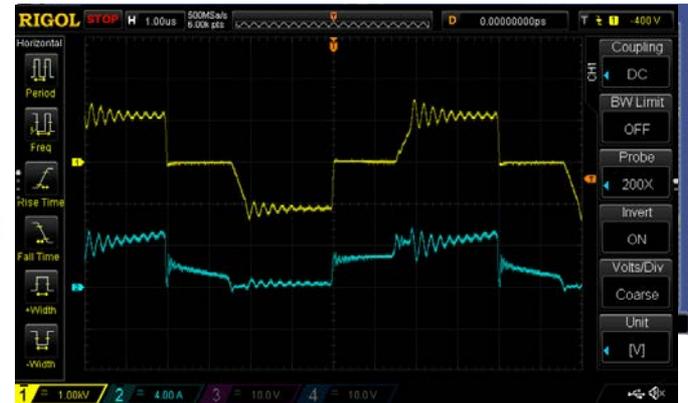
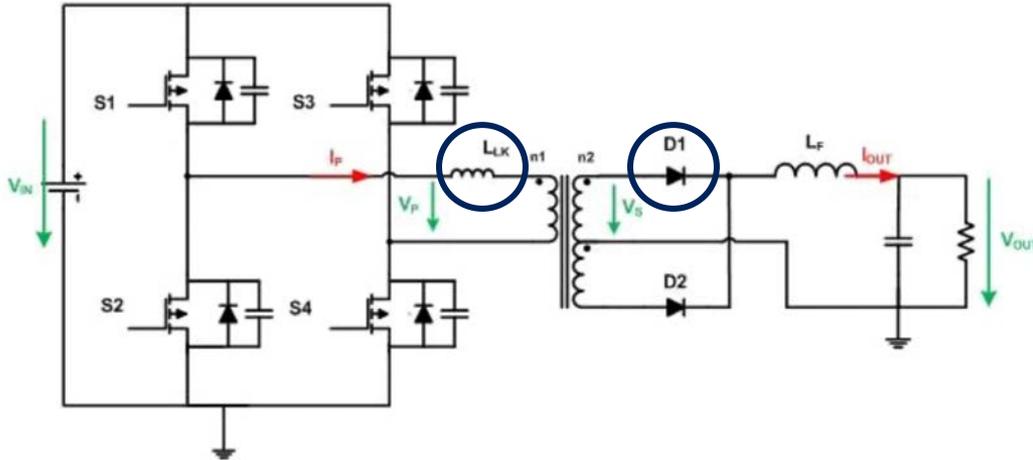
Duty cycle losses

- Due to the leakage inductance, there is a loss of the effective duty cycle in the transformer.
- This effect should be considered in the turns ratio calculations considering the L_{lk} prediction (or goal)



Oscillations

It's very common to find oscillations in the secondary diodes due to the resonance between L_{lk} and the parasitic capacitance of the diodes



ZVS in FBPS

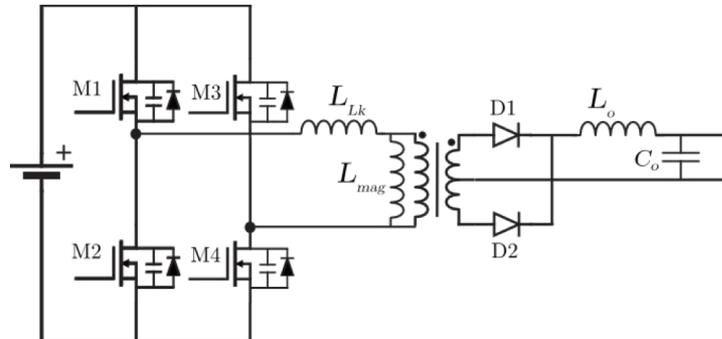
Achieving ZVS in the Full-Bridge Phase Shift is almost mandatory.

ZVS prevents:

- High EMI noise
- Switching losses
- Semiconductor failure rate increase

The main parameters that have an **influence** in achieving ZVS are:

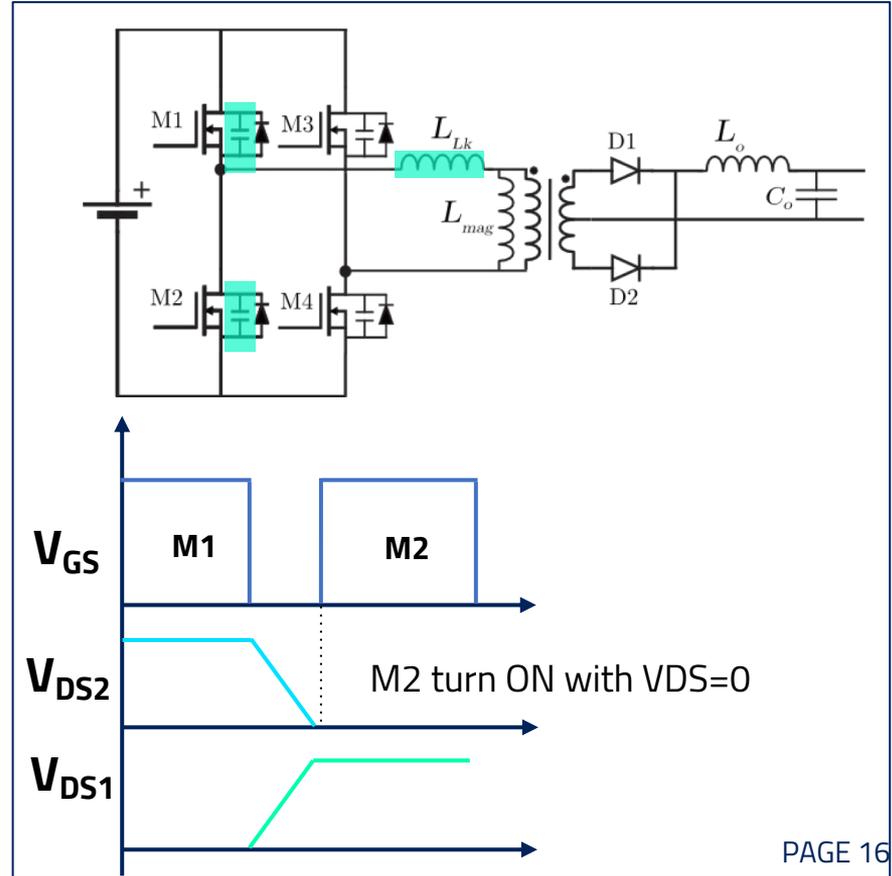
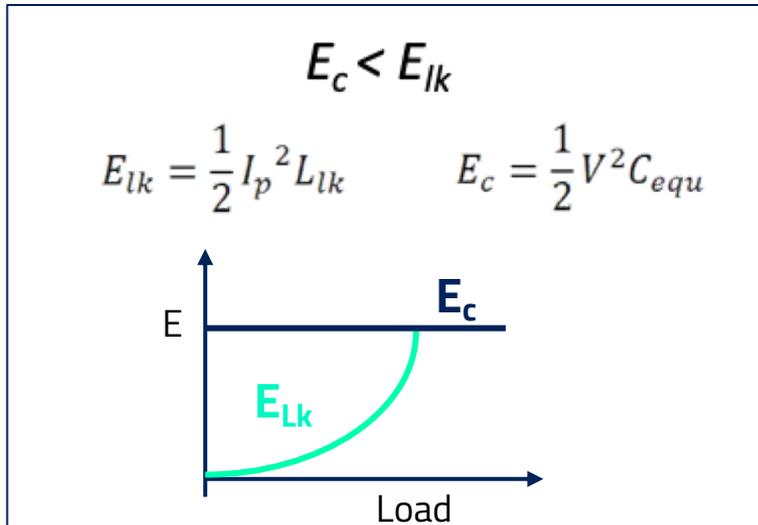
- C_{oss} from the MOSFET
- Transformer parasitics
 - C_{in}
 - L_{mag}
 - L_{Lk}



ZVS conditions

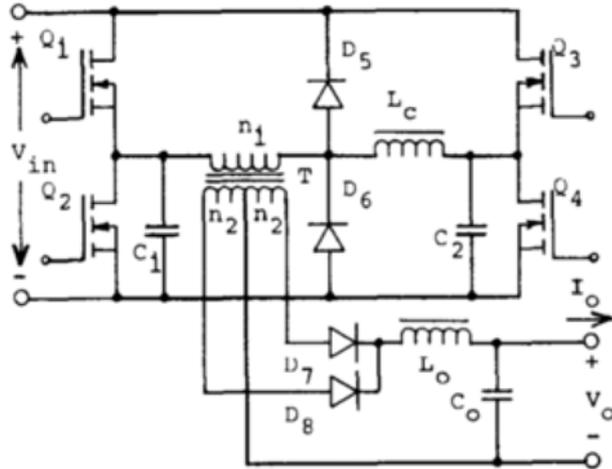
In the phenomenon for discharging the parasitic capacitances, the L_{Lk} is key as explained by [Sabate'90].

If the energy in the L_{Lk} is enough during the dead time for discharging the capacitor, ZVS can be achieved.



ZVS with additional inductance

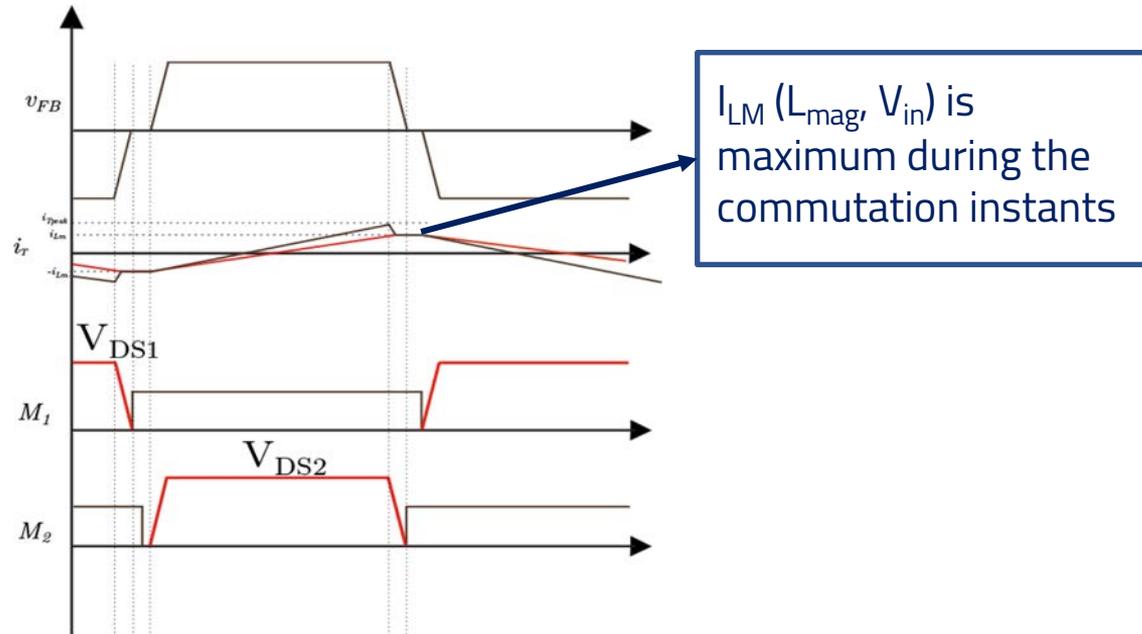
In the publication of Richard Redl [‘90], he introduces an additional “commutating” inductor which extends the ZVS range.



$$E_{LK} + E_{LC} > E_C$$

ZVS with the Magnetizing current

For very light loads, where the energy in the Leakage inductance is very low, ZVS can be achieved using the magnetizing inductance .

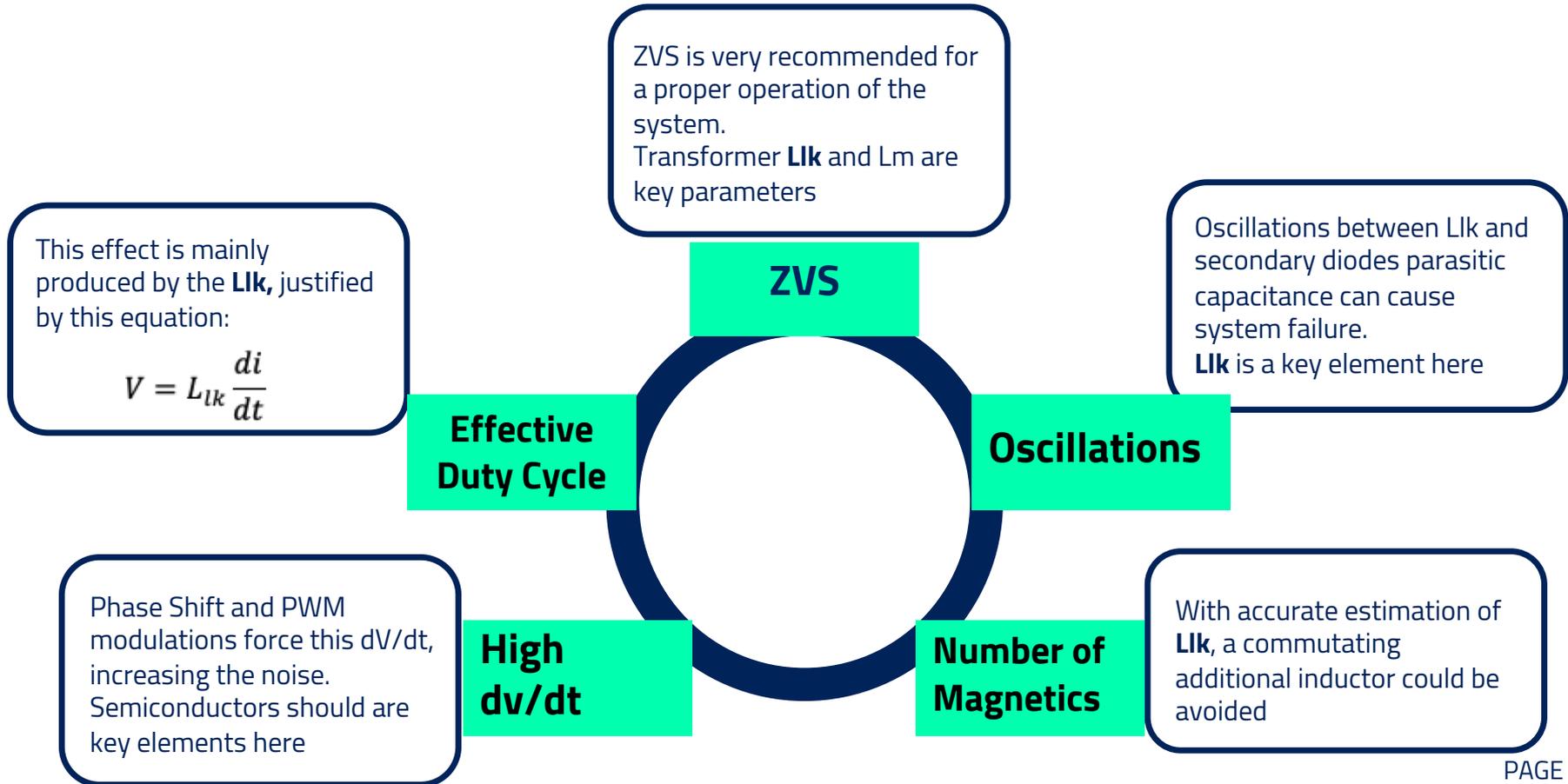


ZVS considerations

Considerations during the design:

- Too much energy stored in the L_{Lk} (or external inductance), produce an increment in the conduction losses in every component through a circulating current.
- For the magnetizing current, the effect is the same.
- The ideal design will have low magnetizing current, and the leakage inductance integrated in the operation for achieving ZVS without additional inductances.

Which are the key parameters?



Conclusion: The transformer is a key element

The importance of the transformer in this converter is huge because is the key element for :

- Design decisions (Semiconductors selection, turns ratio)
- Soft switching
- Number of magnetics
- Implementation (Functionality, PCB design)
- Size (It's the biggest and expensive component)

Transformer parameters

The parameters with high interest in the case of the FBPS (very similar to any case) are:

- Permeability (for the BH model)
- C_{in}
- R_{dc}
- R_{ac}
- L_{mag}
- L_{Lk}

Transformer parameters

The parameters with high interest in the case of the FBPS (very similar to any case) are:

- Permeability (for the BH model)
- C_{in}
- R_{dc}
- R_{ac}
- L_{mag}
- L_{Lk}



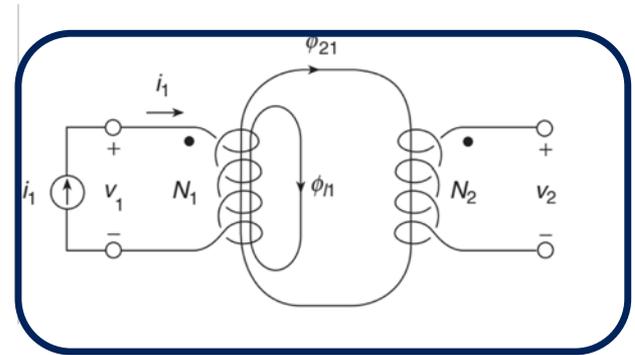
L_{Lk} is selected for this analysis because its influence in the FBPS and the difficulties to accurately predict his value

Leakage Inductance (L_{Lk})

Leakage inductance parasitic effect produced by the imperfect magnetic coupling between the transformer windings. The magnetic flux generated in the primary winding is never transferred 100% to the secondary winding.

This leakage inductance depends basically on:

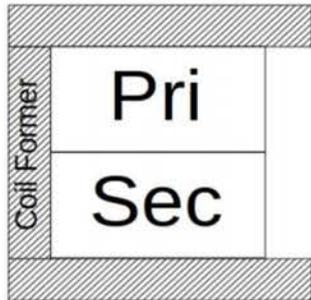
- The winding geometry
- The core geometry
- Number of turns



Impact of winding configuration in L_{Lk}

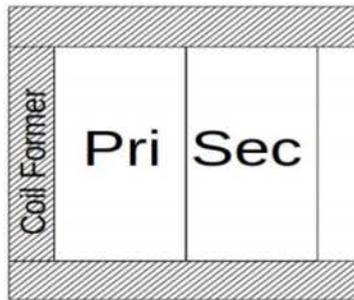
One of the ways of “playing” with this parameter is having different winding strategies. The following configuration strategies provide different coupling results

Configuration 1



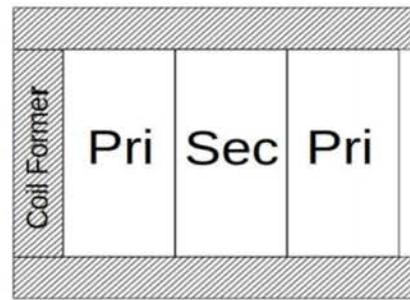
Vertical
windings

Configuration 2



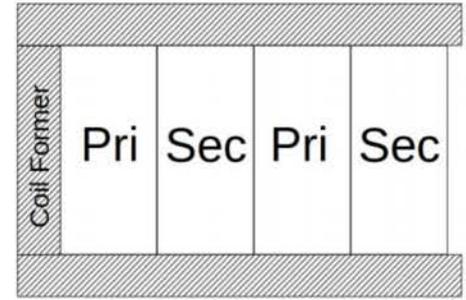
Horizontal
Windings

Configuration 3



Interleaving

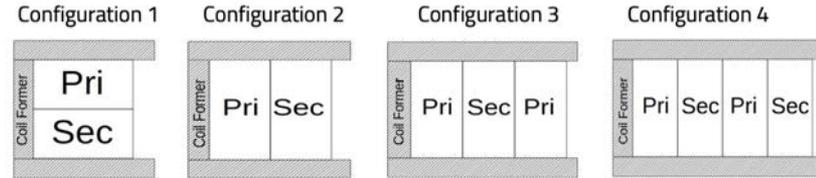
Configuration 4



Doble layer
Interleaving

Impact of winding configuration in L_{Lk}

The results of leakage inductance for 3 cases with 2 different winding configurations



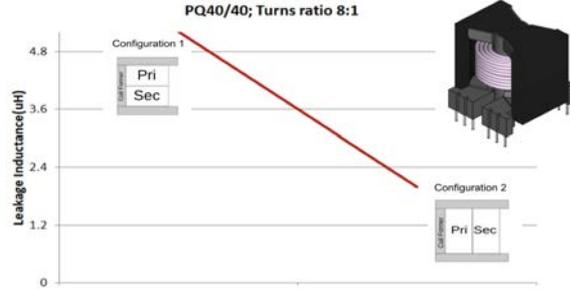
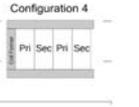
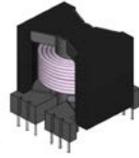
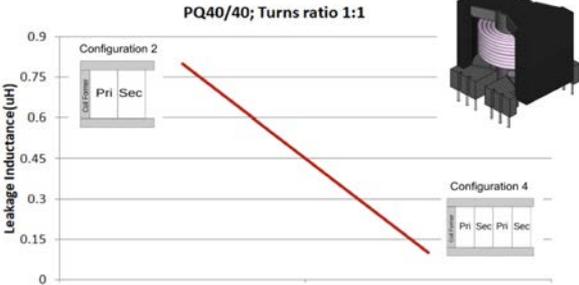
Topology	Application	Power	Core Shape	Turns Ratio	Wire Type	Winding arrangement	L_{lk}
LLC	400 V/ 24 V	1,5 kW	PQ40/40	8:1	Litz	Configuration 1	5.2
LLC	400 V/ 24 V	1,5 kW	PQ40/40	8:1	Litz	Configuration 2	2
DAB	400 V/ 400 V	2 kW	PQ40/40	1:1	Litz	Configuration 2	0.8
DAB	400 V/ 400 V	2 kW	PQ40/40	1:1	Litz	Configuration 4	0.2
Flyback	PFC Flyback	60 W	RM8/I	5:1	Round	Configuration 2	11
Flyback	PFC Flyback	60 W	RM8/I	5:1	Round	Configuration 3	4.7

Table 1: Data of the different converters used in the experiment.

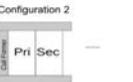
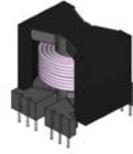


Impact of winding configuration in L_{Lk}

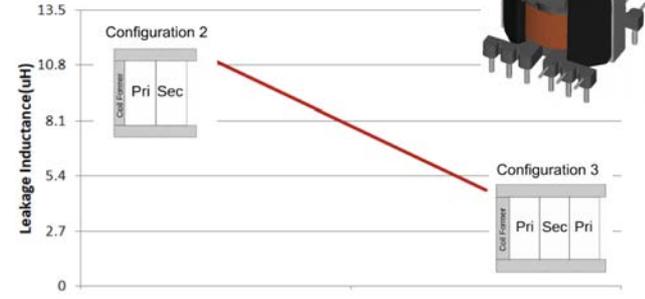
PQ40/40



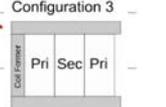
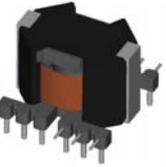
PQ40/40



RM8/I; Turns ratio 5:1



RM8/I



Horizontal 2 layer to 4 layers interleaved
From $L_{lk} = 0.8 \rightarrow 0.2 \mu\text{H}$

Vertical 2 layers to horizontal 2 layer
From $L_{lk} = 5.2 \rightarrow 2 \mu\text{H}$

Horizontal 2 layer to 3 layers interleaved
From $L_{lk} = 11 \rightarrow 4.7 \mu\text{H}$

How can we predict L_{Lk} ?

1. Classic models
2. Trial and error
3. Finite element analysis
4. New math methodologies and ai (fre19)

CLASSICAL MODELS

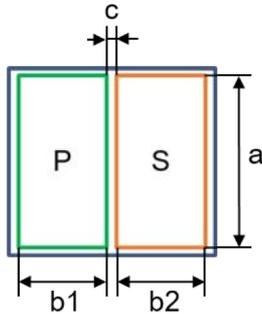


L_{LK} Inductance

A lot of models can be found in literature for calculating the leakage inductance. Two of them are:

CLASSICAL MODEL: This is a simple method for calculating the leakage inductance since only a small number of dimensions are necessary related to the winding geometry.

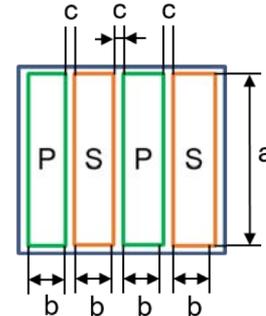
Conventional transformer configuration:



a = winding height (cm)
 b = winding width (cm)
 c = insulation thickness (cm)

$$L_p = \frac{4\pi (MLT) N_p^2}{a} \left(c + \frac{b_1 + b_2}{3} \right) (10^{-9}), \text{ [henrys]}$$

Interleaved transformer configuration:



$$L_p = \frac{\pi (MLT) N_p^2}{a} \left(\Sigma c + \frac{\Sigma b}{3} \right) (10^{-9}), \text{ [henrys]}$$



L_{LK} Inductance

STEPHENS-BOYAJIAN MODEL: This model considers the magnetomotive force distribution and requires detailed knowledge about the winding geometry for calculating the leakage inductance radial and axial components, and the Rogowski factor.

Axial component:
$$L_{\sigma(ax)} = K_{\sigma(ax)} N_p^2 \frac{\mu_0}{h} \sum_{k=1}^n \left[m_k^2 g_k l_{gk} + \left(m_k^2 + m_{k-1}^2 + m_k m_{k-1} \right) w_k l_{wk} / 3 \right]$$

Radial component:
$$L_{\sigma(rad)} = K_{\sigma(rad)} N_p^2 \frac{\mu_0}{w} l_m \sum_{k=1}^n \left[m_k^2 g_k + \left(m_k^2 + m_{k-1}^2 + m_k m_{k-1} \right) h_k / 3 \right].$$

$$L_{\sigma} = L_{\sigma(ax)} + L_{\sigma(rad)}$$

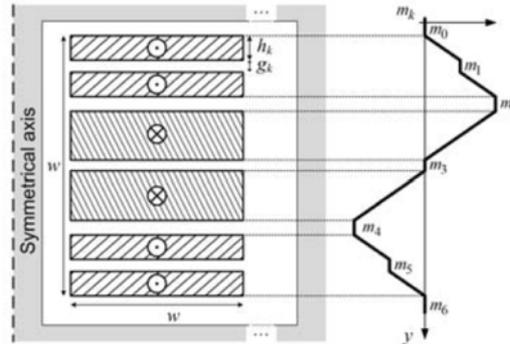


L_{LK} Inductance

STEPHENS-BOYAJIAN MODEL:

Rogowski factor:
$$K_{\sigma(ax)} = 1 - \frac{1 - e^{-\pi h/w}}{\pi h/w} \left\{ 1 - \frac{1}{2} e^{-2\pi g_{01}/w} \left(1 - e^{-\pi h/w} \right) \left[\frac{l_2}{l_m} + \frac{l_1}{l_m} \left(1 + e^{-\pi(g_{02} - g_{01})/w} \right) \right] - \frac{l_1}{l_m} e^{-\pi(h + 2g_{02} + 2g_{01})/w} \right\}$$

Magnetomotive force distribution:



L_{LK} Inductance

When do we use each model?

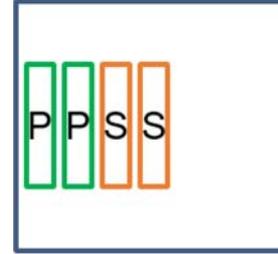
MODEL	WORKS	DOES NOT WORK
CLASSICAL	<ul style="list-style-type: none"> Simple winding arrangements. 	<ul style="list-style-type: none"> Layers with different height. Nonuniform magnetomotive force distributions. High-frequency effects.
STEPHENS-BOYAJIAN	<ul style="list-style-type: none"> Complex winding arrangements. Nonuniform magnetomotive-force distributions. 	<ul style="list-style-type: none"> Layers with different height. High-frequency effects.

L_{LK} Inductance

Leakage inductance comparison in a conventional winding arrangement:

Transformer construction:

- Core shape: PQ40/40
- Core material: Ferroxcube 3F36
- Number turns: 24 / 24
- Wire: Round 12AWG / 12AWG

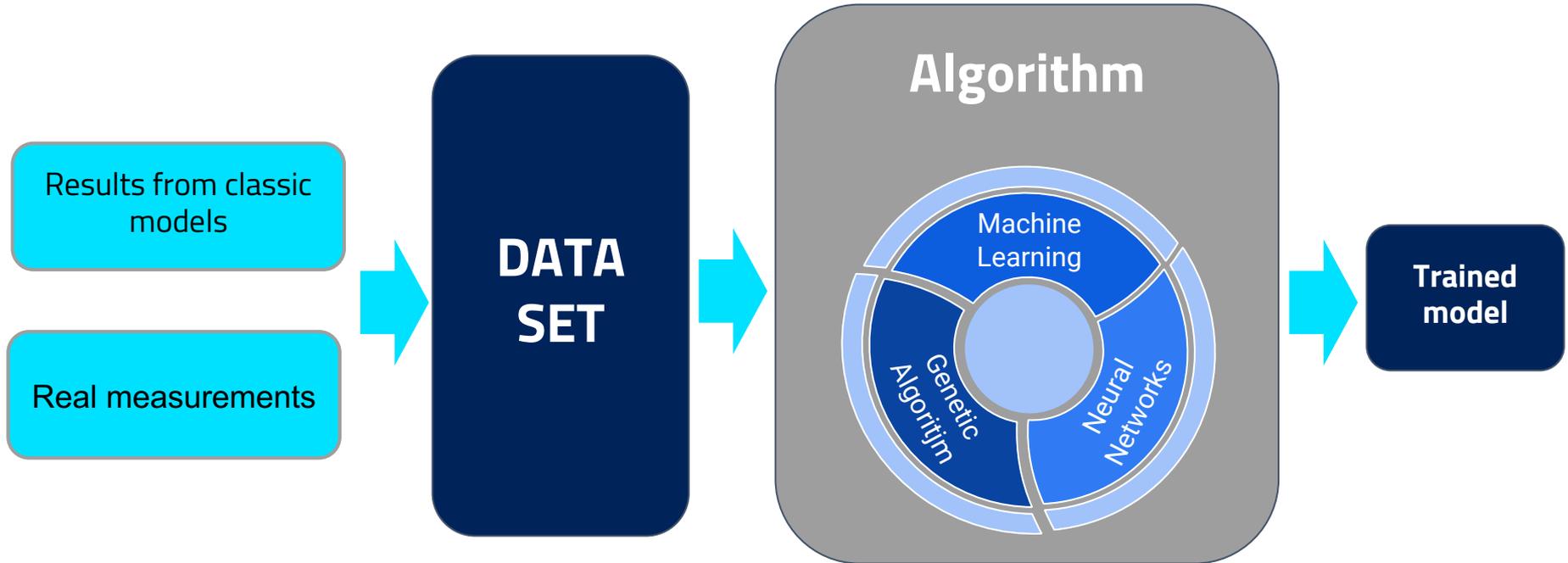


MODEL	CASE A	CASE B	CASE C
CLASSICAL	1.64 μH	6.87 μH	15.69 μH
STEPHENS-BOYAJIAN	1.49 μH	5.65 μH	11.35 μH
MEASUREMENTS	1.01 μH	5.2 μH	5.6 μH

MATHEMATICAL MODELS - AI



AI used for predicting L_{Lk}

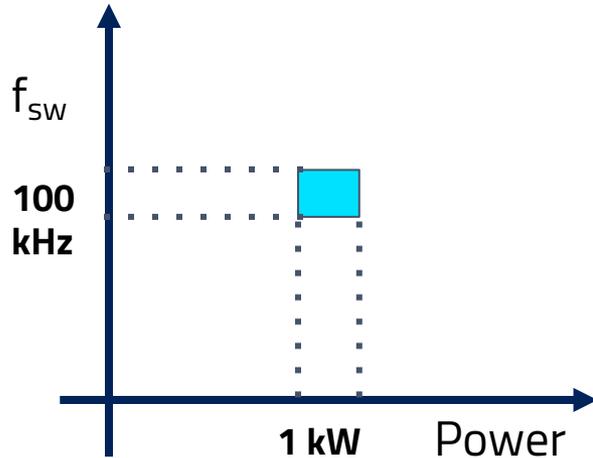


Basic example for predicting L_{LK} in a specific range of power and frequency

Space of data:

Transformer $n=1$

1 kW FBPS & 100 kHz



DATA SET

# Data	Core	Primary number of turns	Primary Litz wire	Real L_{LK}	Model L_{LK}
1	PQ32/30	21	20	2uH	2,2 uH
2	PQ40/40	15	17	8 uH	7 uH
n	PQ50/50	10	14		-	10 uH

Basic example for predicting L_{Lk} in a specific range of power and frequency

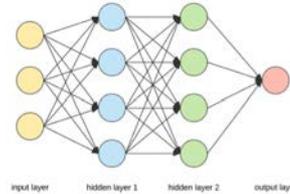
DATA SET

# Data	Core	Primary number of turns	Primary Litz wire	Real L_{Lk}	Model L_{Lk}
1	PQ32/30	21	20	2uH	2,2 uH
2	PQ40/40	15	17	8 uH	7 uH
..
n	ETD59	10	14		10 uH	10 uH



Algorithm

Neural Networks



PQ32/30
N1= 16
N2=18

TRAINED MODEL



$L_{Lk}=2 \text{ uH}$



DESIGN EXAMPLE



FBPS Design Example

The design of a FBPS with the parameters of the Table is designed and the steps for the magnetics are as follow.

Parameter	Value
Rated power	600 W
Min. input voltage	360 V
Nominal input voltage	390 V
Max. input voltage	400 V
Output voltage	300 V
Max. output voltage ripple	3 V

1. According with D_{eff} and input and output voltage range, the turn ratio is calculated
2. The transformer is designed with the lower L_{lk} possible
3. With L_{lk} , the available energy to discharge C_{oss} is known
4. MOSFET are selected considering maximum C_{oss} , power ratios
5. The prototype is built and verified

FBPS Design Example

- Accurate prediction of L_{Lk} helps to have a proper design in the first transformer iteration.
- ZVS is achieved and semiconductors are used without heatsink
- 95% of efficiency is achieved at 500 W



Conclusions

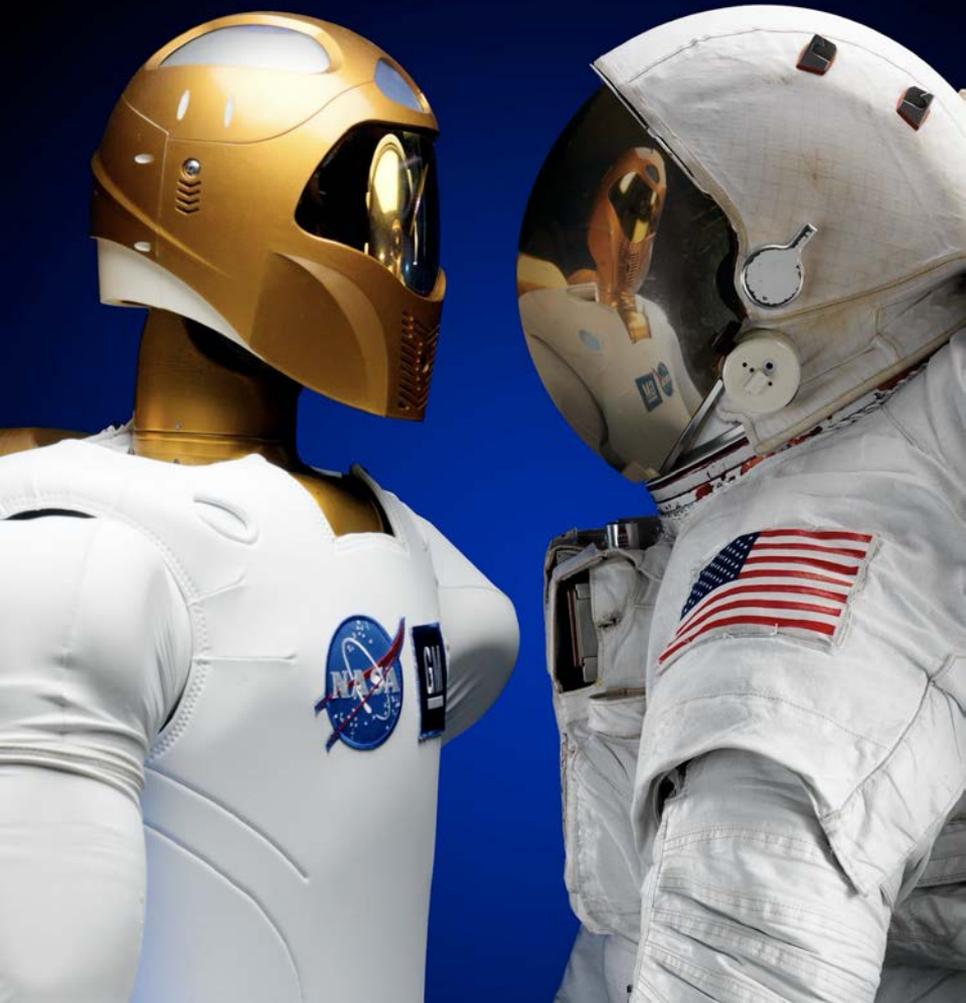
The transformer is the key element in the Full-Bridge performance

Leakage inductance is one of the parameters with more impact

Actual techniques for estimating Leakage inductance are:

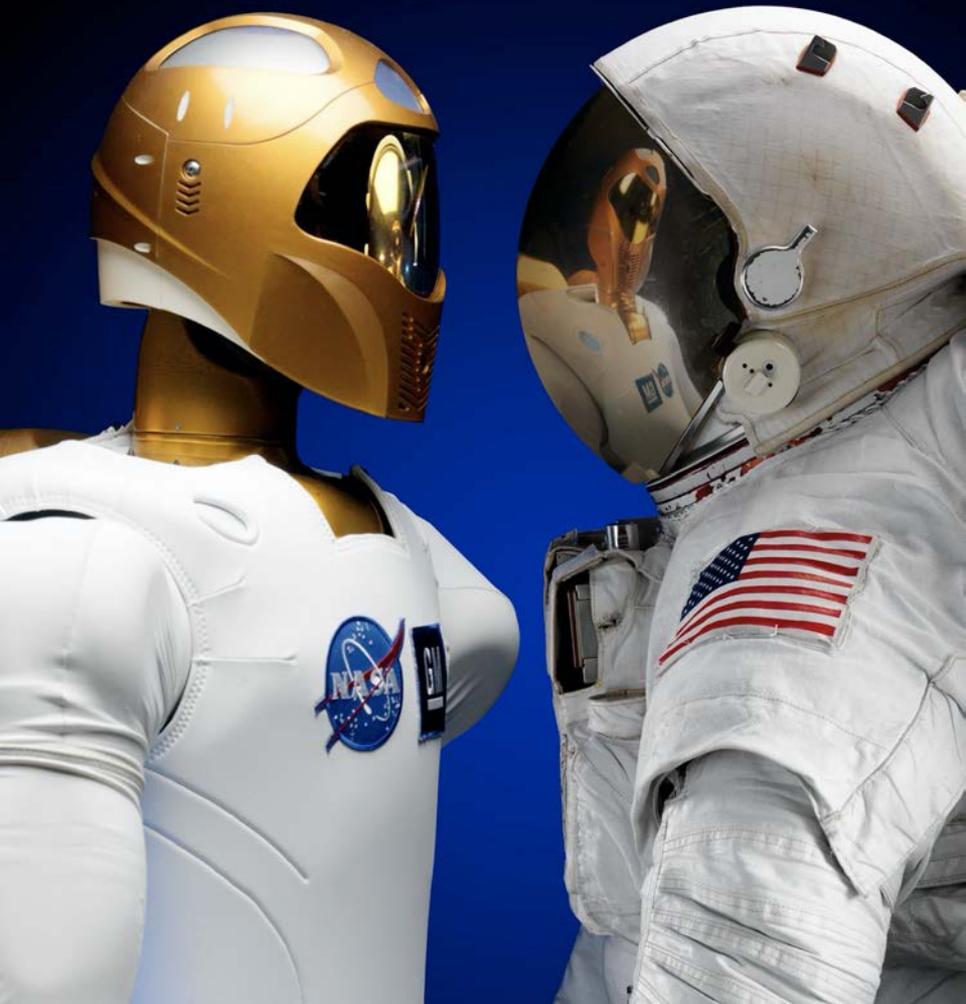
- Not accurate
- Slow
- Not scalable to different cases

Artificial Intelligence methods allows to estimate accurate leakage inductance in seconds.



**What if we extend the AI
to the rest of the
parameters?**

AI can complement classical
models for a better future



THANK YOU

Q&A